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Ceramic nanolaminates—Processing and application

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Abstract

The self-propagating high-temperature synthesis (SHS) has been used in authors' works for preparation of ceramic nanolaminates, namely T_{13} SiC₂, $Ti₃AIC₂$ and T_{i2}AlN. The possibility of obtaining near-single-phase materials, processing of SHS products into sinterable powders and densification of the powders by sintering and hot-pressing are discussed. Finally, polycrystalline nanolaminate materials with controlled phase composition and microstructure have been obtained. The materials have been investigated as structure materials by testing their mechanical properties. The possibility of using of prepared powders to obtain ceramic composites, ceramic bonds and FGM materials, as well as their potential application are discussed. © 2007 Elsevier Ltd. All rights reserved.

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1. Introduction

Among many covalent materials such as carbides or nitrides there is a group of ternary compounds referred in literature as H-phases, Hägg-phases, Novotny-phases or thermodynamically stable nanolaminates. These compounds have an $M_{n+1}AX_n$ stoichiometry, where M is early transition metal, A is an element of A groups (mostly IIIA or IVA) and X is carbon and/or nitrogen. Heterodesmic structures of these phases are hexagonal, P63/mmc and specifically layered. They consist of alternate near-close-packed layers of M_6X octahedrons with dominating covalent bonds and layer of A atoms located at the centre of trigonal prism. The M_6X octahedral, similar to those forming respective binary carbides, are connected one to another by shared edge. Variability of chemical composition of the nanolaminates is usually labelled by the symbol describing their stoichiometry, e.g. $Ti₂AIN$ represents 211 type phase and $Ti₃AIC₂–312$ type one. Structurally, differences between the respective phases consist in the number of M-layers separating the A-layer: in the 211s there are two, whereas in the 321s three M-layers. $1-3$

This paper is focused on preparation of $Ti₃SiC₂$, $Ti₃AlC₂$ and Ti2AlN by self-propagating high-temperature synthesis (SHS). SHS-derived powders were used as for obtaining fully dense polycrystals based on ceramic nanolaminates phases.

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2. Experimental

Many methods were used to prepare the nanolaminate materials. Polycrystalline $Ti₃SiC₂$ was usually obtained in direct reaction of titanium, carbon and silicon for a long time at 1100 ◦C in graphite furnace in argon atmosphere.^{[4](#page-4-0)} The solid-state reaction was also performed by heating of $TiH₂$, Si and graphite mixture at 2000 °C⁵ [o](#page-4-0)r TiC, TiSi₂ and TiSi mixture at 1400 °C.^{[6](#page-4-0)} In a single step reactive hot-pressing dense $Ti₃SiC₂$ materials were synthesized from Ti, SiC and graphite powders.[7](#page-4-0) The other method was melting of Ti, Si and C powders in electric arc at $1200\degree C$.^{[8](#page-4-0)} Attempts to synthesize Ti₃SiC₂ in the polycrystalline form always resulted in materials containing TiC, mostly, and sometimes SiC, as a unwanted phase. Thin films of titanium–silicon carbide were crystallized by CVD method from gaseous titanium, silicon and carbon chlorides in hydrogen or by heating of titanium foil with SiC at $1500\degree C$ in vacuum.^{[9](#page-4-0)}

 $Ti₃AIC₂$ material was firstly prepared by sintering of coldcompacted powder mixtures of titanium, TiAl, Al_4C_3 , and carbon under pure hydrogen for $20 h¹⁰$ Tzenov and Barsoum synthesized bulk titanium–aluminium carbide, containing few amount of corundum, by reactive hot isostatic pressing of a mixture of titanium, aluminium carbide and graphite powders under 70 MPa at 1400° C for 16 h.^{[11](#page-4-0)} Fully dense polycrystalline $Ti₃AIC₂$ was also fabricated by a solid–liquid reaction synthesis and simultaneous *in situ* hot-pressing of a mixture of Ti, Al and graphite powders at 1500 ◦C under 25 MPa for 5 min and subsequent annealing at $1200\degree$ $1200\degree$ C for 20 min.^{12}

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Ti2AlN has been less investigated due to difficulties in processing single-phase bulk material. Titanium–aluminium nitride thin films were formed by reactive magnetron sputtering from a $Ti₂Al compound target in a mixed argon/nitrogen atmosphere.¹³$ $Ti₂Al compound target in a mixed argon/nitrogen atmosphere.¹³$ $Ti₂Al compound target in a mixed argon/nitrogen atmosphere.¹³$ Epitaxial growth^{[14](#page-4-0)} and glow discharge treatment^{[15](#page-4-0)} were also used for preparation of $Ti₂AIN$ coatings on Ti alloys. It was stated that these coatings improved hardness, wear resistance and biocompatibility of the nitrided titanium alloys. Barsoum et al.¹⁶ reported fabrication of bulk Ti₂AlN material using Ti and AlN powders as raw materials. The samples even hotisostatic pressed at 1400 ◦C for 48 h still contained 10–15 vol.% of unwanted phases. Fully dense and single-phase $Ti₂AIN$ material was successfully synthesized by a hot-pressing method using Ti, Al and TiN powders as starting materials.[17](#page-4-0) The process was performed at 1400 ◦C for 1 h under pressure of 25 MPa.

The most successful preparation method of nanolaminate powders has been developed by the authors based on selfpropagating high-temperature synthesis (SHS). Using powders of titanium, silicon and carbon black as reactants, a powder composed mainly of $Ti₃SiC₂$ and of minor amounts of TiC was synthesized.^{[18](#page-4-0)} Following ignition at 1050° C, complete conversion of the reactants to the product was observed in a time of $2-5$ s.

 $Ti₃AIC₂$ synthesis was performed by SHS method using mixture of intermetallic compounds, namely TiAl and $Ti₃Al$, carbon powder and/or titanium powder in the respective molar ratios. The SHS reaction, initiated by local ignition, was performed in argon atmosphere. The products of the synthesis with use of TiAl were TiC as a dominating phase and $Ti₃AIC₂$ as a balance did not exceed 40 wt.%. The larger amounts of $Ti₃AIC₂$ were obtained when Ti₃Al was used as the precursor. In this case double titanium–aluminium carbide was a dominating phase, its amount exceeded 80 wt.%, and the balance was TiC.^{[19](#page-5-0)}

SHS synthesis of $Ti₂AIN$ powder was performed in a similar way. The precursors were TiAl or Ti₃Al powders mixed with titanium or aluminium powders, respectively, and the reaction was conducted in nitrogen. Ti₂AlN accompanied by small amount of TiN, Ti3AlN and Ti3Al was a result of SHS reaction using TiAl as a precursor. Product obtained as a result of the SHS synthesis in Ti3Al with metallic aluminium consists mostly of TiN and $Ti₂AIN$ with some $Ti₃AI$ and AlN. The reaction conducted in mixture of TiAl and Ti₃Al leads to creation of TiN as a dominating phase and small quantities of $Ti₂AIN$, $Ti₃AI$ and AlN. In both titanium–aluminium materials the SHS reaction of the mixture of elements did not show positive results.^{[20](#page-5-0)}

The SHS-derived powders are good sinterable precursors for preparation of dense materials. Typical powders synthesized through SHS have a form of a porous sponge. Because of strong aggregation and agglomeration of the powders caused mainly by high temperature of SHS, reaction-grinding process is usually

applied before densification. Pressureless sintering, hot-pressing and isostatic hot-pressing were successfully applied to obtain dense nanolaminate materials.[21–24](#page-5-0) The applied temperatures differ from 1100 to 1600 \degree C depending on the process and the powder. It is worth to notice that during thermal treatment some structural changes accompanied with phase content changes can be observed. Sintering of $Ti₃SiC₂$ usually causes partially decomposition of this phase and small amounts of TiC and SiC are detected. Heat-treatment of $Ti₃AIC₂$ and $Ti₂AIN$ also lead to formation of TiC and TiN type phases, respectively.[20,23,25](#page-5-0)

3. Results and discussion

3.1. Mechanical properties

The specific structure of such compounds causes an extraordinary set of properties that are not observed in any typical metallic and ceramic material. The nanolaminate materials combine common ceramic properties like high stiffness, moderately low coefficient of thermal expansion and excellent thermal and chemical resistance with low hardness, good compressive strength, high fracture toughness, ductile behaviour as well as good electrical and thermal conductivity characteristic for metals.[3](#page-4-0) The exceptional combination of such properties allows nanolaminate materials to be good machinable even by standard tools. The most interesting features of these materials are their very good mechanical properties. High fracture toughness and possibility of plastic deformation is result of complex fracture mechanism additionally depending on microstructure of the material, especially on grain sizes and their shapes. The mechanical properties of $Ti₃SiC₂$ materials are collected in Table 1. The values originate in the subject literature and our own experiments.[3,26](#page-4-0)

[Fig. 1](#page-2-0) shows Young modulus of $Ti₃AIC₂$ materials prepared from different intermetallic precursors and hot-pressed at temperature range of 1300–1450 ◦C. It can be stated that elastic properties of such materials depend on phase composition changes due to the sintering conditions. Increase of the temperature of hot-pressing accompanied by increase of the TiC content makes materials much stiffer. The similar effect is observed in case of shear modulus changes ([Fig. 2\).](#page-2-0) [Fig. 3](#page-2-0) reveals that low hardness of the materials hot-pressed at lower temperatures, specific for the materials with high contents of $Ti₃AIC₂$, increase for the materials with the higher TiC content sintered at higher temperatures.

Increase of Young modulus caused by increase of the hotpressing temperature is also observed in the $Ti₂AIN$ materials. [Fig. 4](#page-2-0) shows changes of the Young and shear module for $Ti₂AIN$ materials prepared from SHS-derived powder (TiAl and Ti mixture) and hot-pressed at different temperatures. The presence of

Table 1

Mechanical properties of $Ti₃SiC₂$ sintered polycrystals

Fig. 1. Young's modulus of Ti₃AlC₂ materials prepared from different intermetallic precursors and hot-pressed at temperature range of 1300–1450 ◦C.

Fig. 2. Shear modulus of $Ti₃AIC₂$ materials prepared from different intermetallic precursors and hot-pressed at temperature range of 1300–1450 ◦C.

TiN-type phase in the dense materials leads to the improved of their elastic properties.

Values of fracture toughness of these materials, measured by Vicker's indentation method, are presented in Table 2. The

Fig. 3. Vicker's hardness of $Ti₃AIC₂$ materials prepared from different intermetallic precursors and hot-pressed at temperature range of 1300–1450 ◦C.

Fig. 4. Elastic module of Ti₂AlN materials hot-pressed at different temperatures.

Table 2 Fracture toughness of Ti₂AlN materials hot-pressed at different temperatures

Temperature $(^{\circ}C)$	$K_{\rm lc}$ (MPa m ^{0.5})
1100	7.00 ± 0.4
1200	$8.2 + 0.1$
1300	Not measurable

increase of amount of the much stiffer and much toughed TiNtype phase causes increase of the K_{1c} value. It is worth to notice that the sample sintered at 1300 ◦C reveals pseudo-plastic properties similar as pure nanolaminate phases. Fig. 5 presents micrograph of the Vicker indentation made on the polished surface of Ti₂AlN material hot-pressed at 1300 \degree C.

4. Application of Ti₃SiC₂

Because of the most developed methods of preparation, $Ti₃SiC₂$ is the material that has been tested in different applications. Looking for an application as structure machinable ceramics, titanium–silicon carbide was successfully used as a matrix in CMC particulate composites with some other

Fig. 5. Micrograph of the Vicker indentation made on the polished surface of Ti2AlN material hot-pressed at 1300 ◦C.

Fig. 6. Elastic properties of the $Ti₃SiC₂$ -based composites.

covalent phases as inclusions. The SHS-derived powder of titanium–silicon carbide was mixed with the respective amount of TiC, SiC or TiB₂ powders. The materials were hot-pressed at 1500 ◦C for 1 h under 25 MPa. It can be stated that addition of the stiff, covalent inclusions of $TiB₂$ significantly improved elastic properties of the composites (Fig. 6). In other cases, no changes or slightly decrease of the elastic module values can be observed.

Hardness of the composites depends mainly on the inclusion volume fraction (Fig. 7). Addition of the hard inclusions increases of the composite hardness. The larger amount of TiB2 inclusions significantly improved of the composite hardness, whereas the SiC inclusions deteriorate it. All composites have worst bending strength than the pure $Ti₃SiC₂$ matrix but small amount of the inclusion increases their fracture toughness (Figs. 8 and 9). Such behaviour can be explained by complex fracture mechanism of the composites related to their microstructure. [Fig. 10](#page-4-0) shows examples of the crack path in the composites. Crack deflection, and crack branching can be observed in the micrographs.

The specific properties of the $Ti₃SiC₂$ allow using this com-pound as a bonding phase in diamond-based composites.^{[27](#page-5-0)}

Fig. 8. Bending strength of the $Ti₃SiC₂$ -based composites.

Composites were prepared from diamond powders of $3-6 \mu m$ and contained from 20 to 40 wt.% of $Ti₃SiC₂$. They were sintered using a high-pressure apparatus of Bridgman type at 1800 °C under 8 GPa load. Observations of microstructure showed that the relatively large blocky diamond grains of $5-10 \mu m$ were separated by thin channels of fine crystalline material. Hardness of the composites was comparable to the hardness of polycrystalline diamond materials with cobalt bonding phase. The wear tests revealed very good wear resistance of the composites especially the one having 20 wt.% of carbide additions.

Titanium–aluminium carbide can be also used to produce parts of add-on ceramic armour.^{[28,29](#page-5-0)} In this case, $Ti₃SiC₂$ acts as a laminar material combined with metal layer or as a functionally gradient material (FGM) with other ceramics. Such materials might replace currently used ceramic working elements adding the benefit of improved cracking resistance and fracture toughness. FGM of $Ti₃SiC₂-Al₂O₃$ has high damage energy and increased fracture toughness, especially. In order to effectively design functionally gradient materials all constituents need to be well defined in terms of elastic properties (Young's and shear module, Poisson's ratio) as well as thermal properties (thermal expansion coefficient, thermal conductiv-

Fig. 7. Vicker's hardness of the $Ti₃SiC₂$ -based composites.

Fig. 9. Fracture toughness of the $Ti₃SiC₂$ -based composites.

Fig. 10. Crack paths in the $Ti₃SiC₂$ -based composites with: TiC (a), SiC (b) and $TiB₂$ (c) inclusions.

ity). These properties formed a basis for calculation of FGM lamina compositions and properties. Materials were sintered in hot-pressing regime under the pressure of 25 MPa in inert atmosphere of flowing argon at 500° C for 1 h. A gradient in elastic moduli, Poisson ratio, hardness and fracture toughness can be observed in the FGM material. Increasing content of $Ti₃SiC₂$ in FGM laminate results in increasing pseudo-plastic deformation of material during indentation tests. This indicates it was possible to obtain a brittle-to-pseudo-plastic gradient ceramic material, which should have high stroke resistance and be able to work in armour applications.

5. Conclusions

Despite of many research works, the ceramic nanolaminates are the family of new materials that are still before their full recognition. The basic problems are related to obtaining of phase and property controlled polycrystals ready for testing their properties and potential applications. The SHS processing of powders and then their processing into sintered body seems to be one of the most promising techniques. It can be confirmed by, reported in the present paper, tests of applications of such prepared nanolaminates as ceramic machinable composites, bonded phases in diamond tools and compounds in FGM for ceramic armours.

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